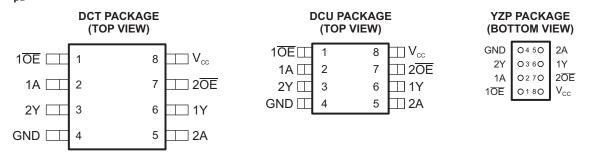
FEATURES

- Available in the Texas Instruments
 NanoFree[™] Package
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max t_{pd} of 1.8 ns at 1.8 V

- Low Power Consumption, 10 μA at 1.8 V
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

This dual buffer/driver is operational at 0.8-V to 2.7-V V_{CC} , but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUC2G240 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

This device is organized as two 1-bit buffers/drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A input to the Y output. When \overline{OE} is high, the outputs are in the high-impedance state.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUC2G240YZPR	UK_
-40°C to 85°C	SSOP - DCT	Reel of 3000	SN74AUC2G240DCTR	U40
	VSSOP - DCU	Reel of 3000	SN74AUC2G240DCUR	UK_

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

⁽²⁾ DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoFree is a trademark of Texas Instruments.



DESCRIPTION/ORDERING INFORMATION (CONTINUED)

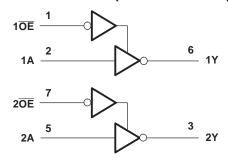
This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

For more information about AUC Little Logic devices, please refer to the TI application report, *Applications of Texas Instruments AUC Sub-1-V Little Logic Devices*, literature number SCEA027.

FUNCTION TABLE (EACH BUFFER)

INP	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	L
L	L	Н
Н	X	Z

LOGIC DIAGRAM (POSITIVE LOGIC)





SN74AUC2G240 **DUAL BUFFER/DRIVER** WITH 3-STATE OUTPUTS

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	3.6	V
VI	Input voltage range ⁽²⁾		-0.5	3.6	V
Vo	Voltage range applied to any output in the I	-0.5	3.6	V	
Vo	Output voltage range ⁽²⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±100	mA
		DCT package		220	
θ_{JA}	Package thermal impedance (3)	DCU package		227	°C/W
		YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions(1)

			MIN	MAX	UNIT	
V_{CC}	Supply voltage		0.8	2.7	V	
		V _{CC} = 0.8 V	V _{CC}			
V_{IH}	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7			
		V _{CC} = 0.8 V		0		
V_{IL}	Low-level input voltage	vel input voltage $V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		
V_{I}	Input voltage		0	3.6	V	
V	Output voltage	Active state	0	V_{CC}	V	
Vo	Output voltage	3-state	0	3.6	V	
		$V_{CC} = 0.8 \text{ V}$		-0.7		
		V _{CC} = 1.1 V		-3		
I_{OH}	High-level output current	V _{CC} = 1.4 V		- 5	mA	
		V _{CC} = 1.65 V		-8		
		V _{CC} = 2.3 V		- 9		
		V _{CC} = 0.8 V		0.7		
		V _{CC} = 1.1 V		3		
I_{OL}	Low-level output current	V _{CC} = 1.4 V		5	mA	
		V _{CC} = 1.65 V		8		
		V _{CC} = 2.3 V		9		
		$V_{CC} = 0.8 \text{ V to } 1.65 \text{ V}^{(2)}$		20		
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}^{(3)}$		20	ns/V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}^{(3)}$		20		
T _A	Operating free-air temperature		-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽²⁾ The data was taken at $C_L = 15$ pF, $R_L = 2$ k Ω (see Figure 1). (3) The data was taken at $C_L = 30$ pF, $R_L = 500$ Ω (see Figure 1).



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER	TEST CONDITION	S	V _{cc}	MIN	TYP ⁽¹⁾	MAX	UNIT
		$I_{OH} = -100 \mu A$		0.8 V to 2.7 V	V _{CC} - 0.1			
		$I_{OH} = -0.7 \text{ mA}$		0.8 V		0.55		
M		$I_{OH} = -3 \text{ mA}$		1.1 V	0.8			V
V _{OH}		$I_{OH} = -5 \text{ mA}$		1.4 V	1			V
		$I_{OH} = -8 \text{ mA}$		1.65 V	1.2			
	$I_{OH} = -9 \text{ mA}$		2.3 V	1.8				
		I _{OL} = 100 μA		0.8 V to 2.7 V			0.2	
		$I_{OL} = 0.7 \text{ mA}$		0.8 V		0.25		
N/	I _{OL} = 3 mA		1.1 V			0.3	3 V	
V _{OL}		$I_{OL} = 5 \text{ mA}$ 1.4 V $I_{OL} = 8 \text{ mA}$ 1.65 V				0.4	V	
				1.65 V			0.45	
		I _{OL} = 9 mA		2.3 V			0.6	
I _I A	or OE inputs	V _I = V _{CC} or GND		0 to 2.7 V			±5	μΑ
I _{off}		V_I or $V_O = 2.7 V$		0			±10	μΑ
I_{OZ}		V _O = V _{CC} or GND		2.7 V			±10	μΑ
I _{CC}		$V_I = V_{CC}$ or GND,	$I_O = 0$	0.8 V to 2.7 V		·	10	μΑ
C _i		V _I = V _{CC} or GND		2.5 V		2.5		pF
C _o		V _O = V _{CC} or GND		2.5 V		5.5		pF

⁽¹⁾ All typical values are at $T_A = 25$ °C.

Switching Characteristics

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 1)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 0.8 V	V _{CC} = ± 0.	1.2 V 1 V		1.5 V .1 V		_C = 1.8 : 0.15 \		V _{CC} = ± 0.		UNIT
	(INPOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX		
	t _{pd}	Α	Υ	4.5	0.9	3.3	0.7	2.2	0.5	1.2	1.8	0.5	1.3	ns
	t _{en}	ŌĒ	Υ	5.6	0.9	4.1	0.7	2.5	0.6	1.4	2.1	0.6	1.5	ns
	t _{dis}	ŌĒ	Y	5.8	1.9	4.8	1.5	3.8	1.8	2.8	4	1.4	2.9	ns

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C	_C = 1.8 \ 0.15 V	٧	V _{CC} = 1 ± 0.2	2.5 V 2 V	UNIT
	(INPUT)	(001F01)	MIN	TYP	MAX	MIN	MAX	
t _{pd}	A	Υ	0.7	1.5	2.5	0.6	1.7	ns
t _{en}	ŌĒ	Υ	0.9	1.7	3.1	0.8	2.1	ns
t _{dis}	ŌĒ	Υ	1.5	1.8	3.7	0.8	1.9	ns

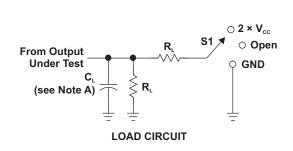
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC} = 0.8 V TYP	V _{CC} = 1.2 V TYP	V _{CC} = 1.5 V TYP	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	15	15	15	15	17	pF

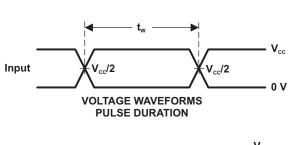


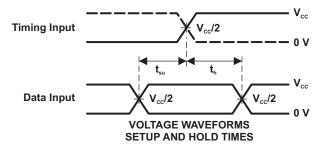
PARAMETER MEASUREMENT INFORMATION

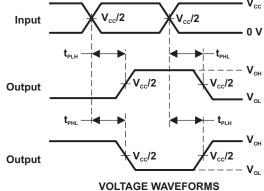


TEST	S1
t _{PLH} /t _{PHL}	Open
t_{PLZ}/t_{PZL}	2 × V _{cc}
t _{PHZ} /t _{PZH}	GND

V _{cc}	C _∟	R _L	V _Δ
0.8 V	15 pF	2 k Ω	0.1 V
1.2 V ± 0.1 V	15 pF	2 k Ω	0.1 V
$1.5 \ V \pm 0.1 \ V$	15 pF	2 k Ω	0.1 V
1.8 V ± 0.15 V	15 pF	2 k Ω	0.15 V
$2.5~V~\pm~0.2~V$	15 pF	2 k Ω	0.15 V
1.8 V ± 0.15 V	30 pF	1 k Ω	0.15 V
$2.5 V \pm 0.2 V$	30 pF	500 Ω	0.15 V
		I	I

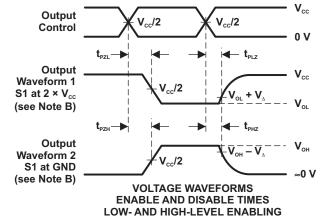






PROPAGATION DELAY TIMES

INVERTING AND NONINVERTING OUTPUTS



NOTES: A. C. includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_o = 50 Ω, slew rate ≥ 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and \dot{t}_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. $t_{\text{\tiny PLH}}$ and $t_{\text{\tiny PHL}}$ are the same as $t_{\text{\tiny pd}}$.

Figure 1. Load Circuit and Voltage Waveforms

www.ti.com 23-May-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
	. ,				. ,	(4)	(5)		
SN74AUC2G240DCTR	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU SN NIPDAU	Level-1-260C-UNLIM	-40 to 85	(2XA5, U40) (R, Z)
SN74AUC2G240DCTR.B	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(2XA5, U40) (R, Z)
SN74AUC2G240DCUR	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(U40Q, U40R)
SN74AUC2G240DCUR.B	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(U40Q, U40R)

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUC2G240DCTR	SSOP	DCT	8	3000	180.0	13.0	3.35	4.5	1.55	4.0	12.0	Q3
SN74AUC2G240DCUR	VSSOP	DCU	8	3000	178.0	9.5	2.25	3.35	1.05	4.0	8.0	Q3
SN74AUC2G240DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUC2G240DCTR	SSOP	DCT	8	3000	182.0	182.0	20.0
SN74AUC2G240DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74AUC2G240DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-187 variation CA.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.





NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated